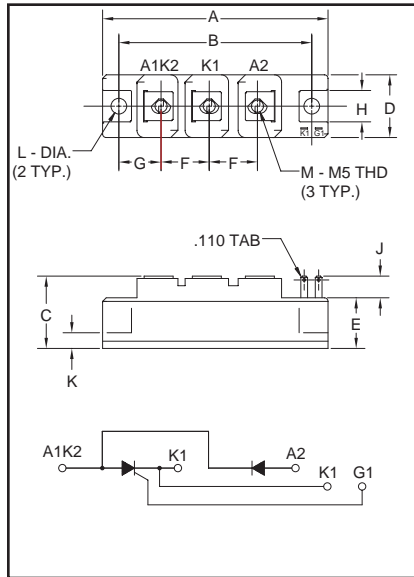


SCR/Diode POW-R-BLOK™ Modules 55 Amperes/800 Volts



Outline Drawing

Dimension	Inches	Millimeters
A	3.681	93.5
B	3.150±0.012	80±0.3
C	1.181	30
D	1.024	26
E	0.827	21
F	0.787	20
G	0.689	17.5
H	0.492	12.5
J	0.354	9
K	0.256	6.5
L	0.256±0.008 Dia. Dia. 6.5±0.2	
M	M5 Metric	M5



CM420855
SCR/Diode
POW-R-BLOK™ Modules
55 Amperes/800 Volts

Description:

Powerex SCR/Diode POW-R-BLOK™ Modules are designed for use in applications requiring Half-Control and isolated packaging. The modules are isolated for easy mounting with other components on common heatsinks.

Features:

- Isolated Mounting
- Glass Passivated Chips
- Metal Baseplate
- Low Thermal Impedance

Applications:

- Battery Supplies
- Bridge Circuits
- AC and DC Motor Control
- Tap Changers
- Lighting Control

Ordering Information:

Select the complete eight digit module part number you desire from the table below. Example: CM420855 is an 800 Volt, 55 Ampere SCR/Diode POW-R-BLOK™ Module.

Type	Voltage Volts (x100)	Current Rating Amperes (55)
CM42	08	55



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM420855

SCR/Diode POW-R-BLOK™ Modules

55 Amperes/800 Volts

Absolute Maximum Ratings

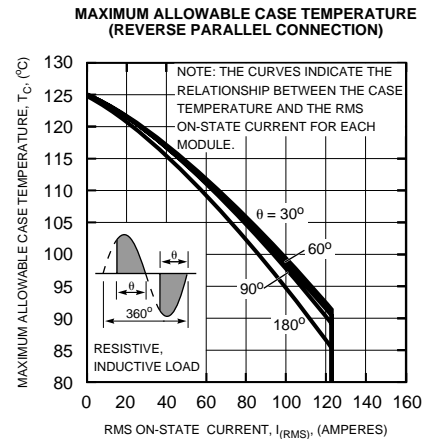
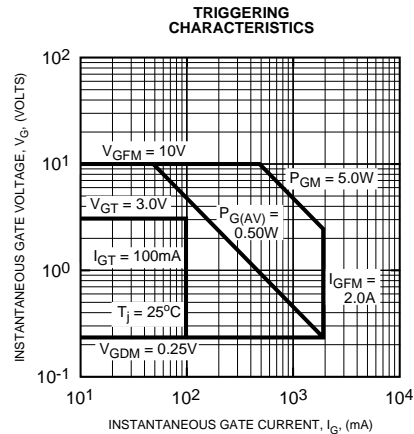
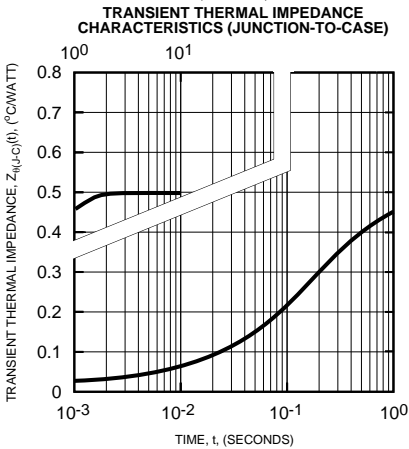
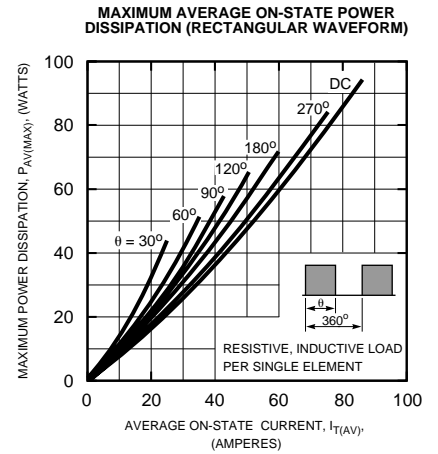
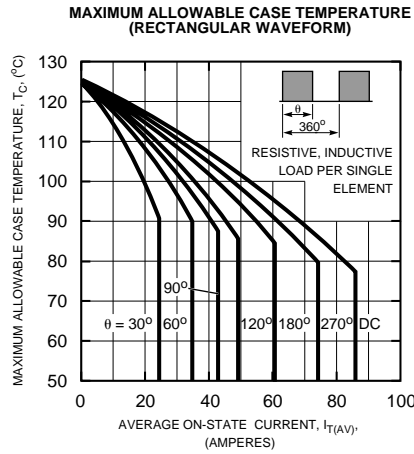
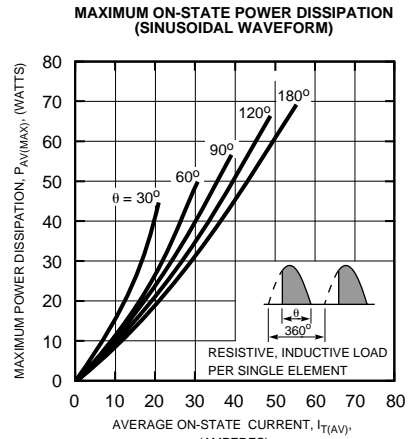
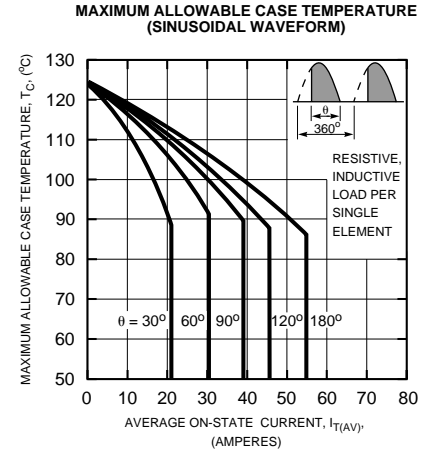
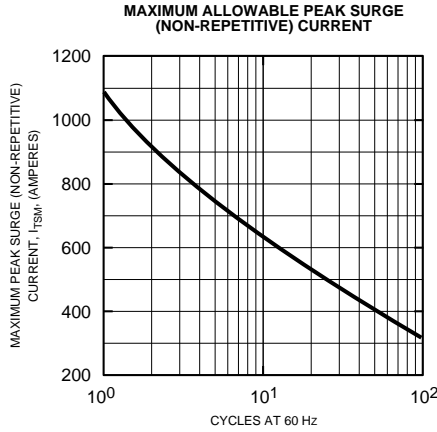
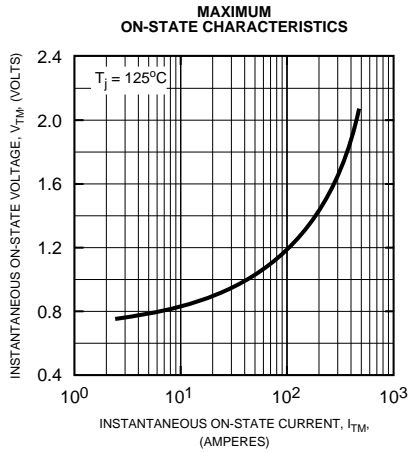
Characteristics	Symbol	CM420855	Units
Peak Forward Blocking Voltage	V_{DRM}	800	Volts
Transient Peak Forward Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{DSM}	960	Volts
DC Forward Blocking Voltage	$V_{D(DC)}$	640	Volts
Peak Reverse Blocking Voltage	V_{RRM}	800	Volts
Transient Peak Reverse Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{RSM}	960	Volts
DC Reverse Blocking Voltage	$V_{R(DC)}$	640	Volts
RMS On-State Current	$I_{T(RMS)}$; $I_{F(RMS)}$	86	Amperes
Average On-State Current, $T_C = 86^\circ C$	$I_{T(AV)}$; $I_{F(AV)}$	55	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM} ; I_{FSM}	1100	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM} ; I_{FSM}	1000	Amperes
I^2t (for Fusing), 8.3 milliseconds	I^2t	5000	A ² sec
Critical Rate-of-Rise of On-State Current*	di/dt	100	Amperes/ μs
Peak Gate Power Dissipation	P_{GM}	5.0	Watts
Average Gate Power Dissipation	$P_{G(AV)}$	0.5	Watts
Peak Forward Gate Voltage	V_{GFM}	10	Volts
Peak Reverse Gate Voltage	V_{GRM}	5.0	Volts
Peak Forward Gate Current	I_{GFM}	2.0	Amperes
Storage Temperature	T_{STG}	-40 to 125	$^\circ C$
Operating Temperature	T_j	-40 to 125	$^\circ C$
Maximum Mounting Torque M6 Mounting Screw	—	26	in.-lb.
Maximum Mounting Torque M5 Terminal Screw	—	17	in.-lb.
Module Weight (Typical)	—	160	Grams
V Isolation	V_{RMS}	2000	Volts

* $T_j = 125^\circ C$, $I_G = 0.5A$, $V_D = 1/2 V_{DRM}$

Electrical and Thermal Characteristics, $T_j = 25^\circ C$ unless otherwise specified

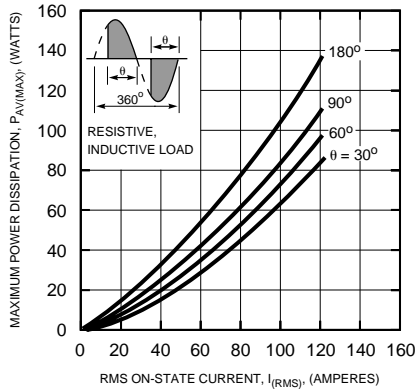
Characteristics	Symbol	Test Conditions	CM420855	Units
Blocking State Maximums				
Forward Leakage Current, Peak	I_{DRM}	$T_j = 125^\circ C$, $V_{DRM} = \text{Rated}$	10	mA
Reverse Leakage Current, Peak	I_{RRM}	$T_j = 125^\circ C$, $V_{RRM} = \text{Rated}$	10	mA
Conducting State Maximums				
Peak On-State Voltage	V_{FM} , V_{TM}	$I_{FM} = 165A$, $I_{TM} = 165A$	1.35	Volts
Switching Minimums				
Critical Rate-of-Rise of Off-State Voltage	dv/dt	$T_j = 125^\circ C$, $V_D = 2/3 V_{DRM}$	500	Volts/ μs
Thermal Maximums				
Thermal Resistance, Junction-to-Case	$R_{\theta(J-C)}$	Per Module	0.5	$^\circ C/Watt$
Thermal Resistance, Case-to-Sink (Lubricated)	$R_{\theta(C-S)}$	Per Module	0.2	$^\circ C/Watt$
Gate Parameters Maximums				
Gate Current-to-Trigger	I_{GT}	$V_D = 6V$, $R_L = 2\Omega$	100	mA
Gate Voltage-to-Trigger	V_{GT}	$V_D = 6V$, $R_L = 2\Omega$	3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_j = 125^\circ C$, $V_D = 1/2 V_{DRM}$	0.25	Volts

CM420855
SCR/Diode POW-R-BLOK™ Modules
 55 Amperes/800 Volts



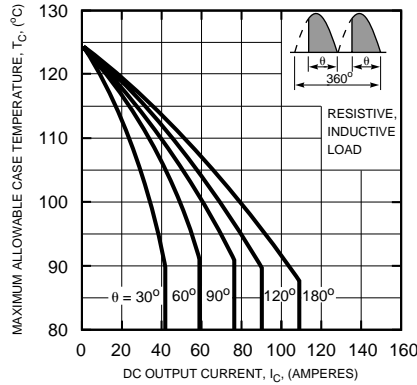
CM420855
SCR/Diode POW-R-BLOK™ Modules
 55 Amperes/800 Volts

MAXIMUM ON-STATE POWER DISSIPATION (REVERSE PARALLEL CONNECTION)



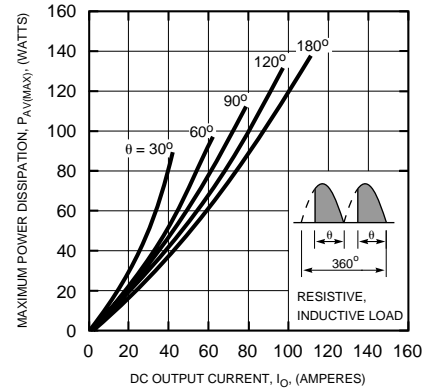
NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE AVERAGE ON-STATE POWER DISSIPATION PER MODULE AND THE RMS ON-STATE CURRENT.

MAXIMUM ALLOWABLE CASE TEMPERATURE (SINGLE PHASE BRIDGE CONNECTION)



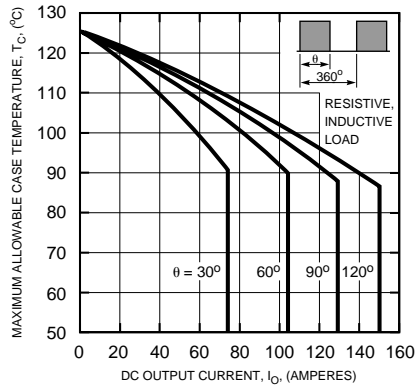
NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE CASE TEMPERATURE AND THE DC OUTPUT CURRENT (FOR TWO ELEMENTS) WHEN USED IN THE SINGLE PHASE BRIDGE CONFIGURATION.

MAXIMUM ON-STATE POWER DISSIPATION (SINGLE PHASE BRIDGE CONNECTION)



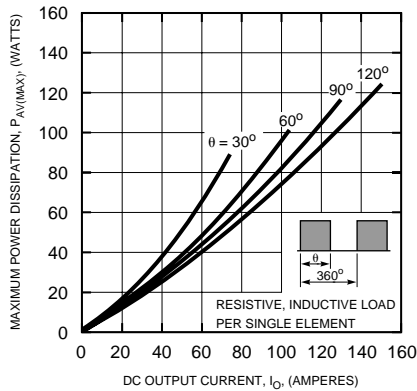
NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE AVERAGE ON-STATE POWER DISSIPATION AND THE DC OUTPUT CURRENT FOR THE SINGLE PHASE BRIDGE CONFIGURATION (POWER DISSIPATION EXPRESSED FOR EACH MODULE AND DC OUTPUT CURRENT EXPRESSED FOR THE PAIR)

MAXIMUM ALLOWABLE CASE TEMPERATURE (THREE PHASE BRIDGE CONNECTION)



NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE CASE TEMPERATURE AND THE DC OUTPUT CURRENT (FOR THREE MODULES) IN THE THREE PHASE CONFIGURATION.

MAXIMUM ON-STATE POWER DISSIPATION (THREE PHASE BRIDGE CONNECTION)



NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE ON-STATE POWER DISSIPATION (PER MODULE) AND THE DC OUTPUT CURRENT (FOR THREE MODULES) IN THE THREE PHASE BRIDGE CONFIGURATION.



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